

### **Features**

- Very Low FOM R<sub>DS(on)</sub>×Q<sub>g</sub>
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## **Maximum Ratings**

Operating Junction Temperature Range : -55°C to +150°C

Storage Temperature Range: -55°C to +150°C

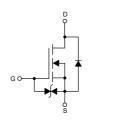
• Thermal Resistance: 3.6°C/W Junction to Case

Paramete	Symbol	Rating	Unit	
Drain-Source Voltage	V <sub>DS</sub>	800	V	
Gate-Source Volltage		V <sub>GS</sub>	±30	V
Continuous Drain Current	I <sub>D</sub>	6	Α	
Pulsed Drain Current (Note	I <sub>DM</sub>	18	Α	
Single Pulse Avalanche E	E <sub>AS</sub>	170	mJ	
Total Power Dissipation	T <sub>C</sub> =25°C	P <sub>D</sub>	35	W

Note: 1.Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.

2.  $V_{DD}$ =50V,  $R_G$ =25 $\Omega$ , Starting  $T_J$ =25 $^{\circ}$ C .

## **Internal Structure and Marking Code**

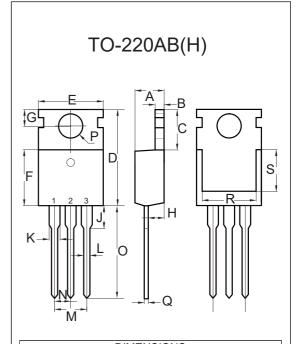




3. Source



# N-CHANNEL Super-Junction Power MOSFET



	DIMENSIONS					
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.172	0.188	4.37	4.77		
В	0.049	0.057	1.25	1.45		
С	0.246	0.270	6.25	6.85		
D	0.594	0.634	15.10	16.10		
E	0.382	0.406	9.70	10.30		
F	0.346	0.370	8.80	9.40		
G	0.102	0.118	2.60	3.00		
Н	0.087	0.102	2.20	2.60		
J		0.134		3.40		
K	0.046	0.058	1.17	1.47		
L	0.028	0.037	0.70	0.95		
М	0.200 BSC		5.08 BSC			
N	0.100 BSC		2.54 BSC			
0	0.502	0.543	12.75	13.80		
Р	0.134	0.150	3.40	3.80	Ф	
Q	0.016	0.026	0.40	0.65		
R	0.276		7.00			
S	0.217		5.50			



# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

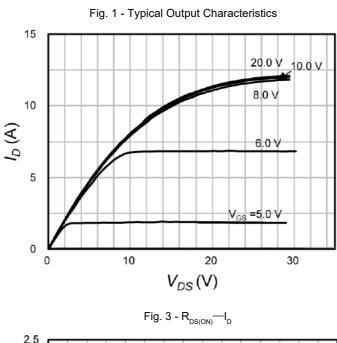
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics	1					I
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	800			V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±10	μA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =800V, V <sub>GS</sub> =0V			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.5	3.5	4.5	V
Drain-Source On-Resistance <sup>(Note 3)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =2.5A		0.95	1.2	Ω
Gate Resistance	$R_G$	V <sub>GS</sub> =0V, f=1.0MHz		21		Ω
Dynamic Characteristics (Note 4)				ı	ı	
Input Capacitance	C <sub>iss</sub>			349		
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V,f=400kHz		16		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			0.9		
Total Gate Charge	$Q_g$			10.6		nC
Gate-Source Charge	$Q_{gs}$	V <sub>DD</sub> =640V,V <sub>GS</sub> =10V,I <sub>D</sub> =4.5A		3.3		
Gate-Drain Charge	$Q_{gd}$			4.5		
Turn-On Delay Time	t <sub>d(on)</sub>			16		
Turn-On Rise Time	t <sub>r</sub>	$V_{DD} = 400V, I_D = 4.5A, R_G = 25\Omega$		24		ns
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>DD</sub> -400V, I <sub>D</sub> -4.5A,R <sub>G</sub> -25Ω		59		
Turn-Off Fall Time	t <sub>f</sub>			19		
Drain-Source Body Diode Cha	racteristi	cs				
Continuous Body Diode Current	Is	T <sub>C</sub> =25°C			6	
Pulsed Diode Forward Current	I <sub>SM</sub>	16-23 0			18	Α
Body Diode Voltage	V <sub>SD</sub>	I <sub>SD</sub> =4.5A, V <sub>GS</sub> =0V			1.4	V
Reverse Recovery Time	t <sub>rr</sub>			380		ns
Reverse Recovery Charge	$Q_{rr}$	$V_{DD}$ =100V, $I_F$ = $I_S$ , $di_F$ / $dt$ =100A/ $\mu$ s		2		μC
Reverse Recovery Current	I <sub>rrm</sub>			11		Α

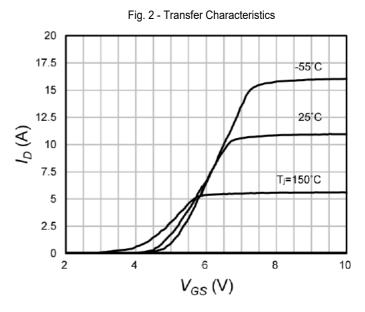
Note 3. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤ 1%.

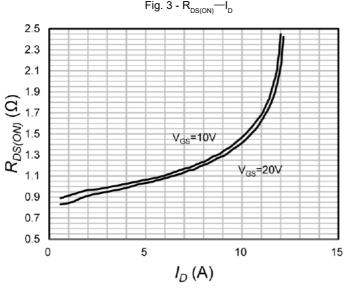
<sup>4.</sup> Guaranteed by Design, Not Subject to Production Testing.

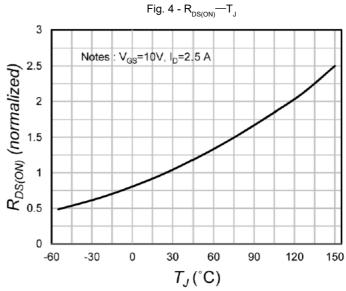


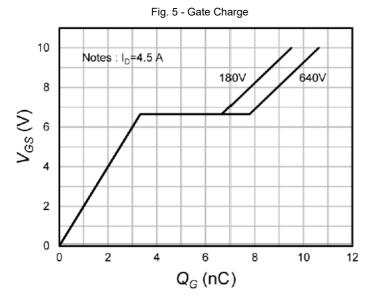
#### **Curve Characteristics**

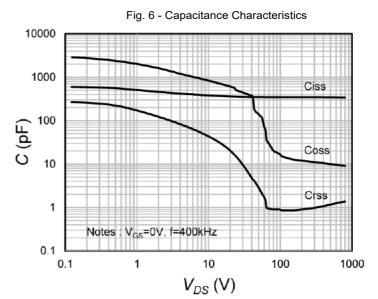






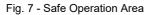








## **Curve Characteristics**



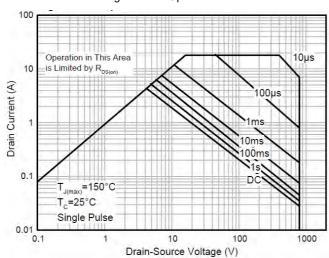
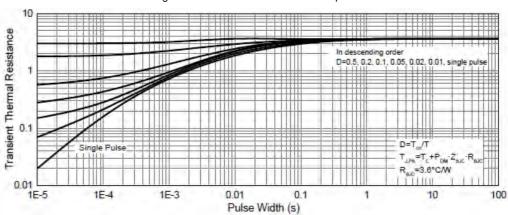


Fig.8 - Maximum Transient Thermal Impedance



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## **Ordering Information**

Device	Packing
Part Number-BP	Bulk:50pcs/Tube,1Kpcs/Box,5Kpcs/Carton

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-BP-HF

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